

<b>INFORMATION DISCLOSURE CITATION</b> <i>(Use several sheets if necessary)</i>				Docket Number (Optional) <b>50478-3700</b>		Application Number <b>10/591153</b>		<b>30 AUG 2006</b> Not yet assigned			
				Applicant(s) <b>Hideo Nagai et al.</b>						<b>10/591153</b>	
				Filing Date <b>Herewith</b>				Group Art Unit <b>Not yet assigned</b>			
<b>U. S. PATENT DOCUMENTS</b>											
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE				
		6,222,207	4.24.2001	Carter-Coman et al.							
		6,316,785	11.13.2001	Nunoue et al.							
<b>U.S. PATENT APPLICATION PUBLICATIONS</b>											
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE				
		2004-0031956	2.19.2004	Saxler							
<b>FOREIGN PATENT DOCUMENTS</b>											
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES NO				
		2003-110138	4.11.2003	Japan w/English Abstract			X				
		11-330552	11.30.1999	Japan w/English Abstract			X				
<b>OTHER DOCUMENTS</b> <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>											
		Yamada, Motokazu et al; InGaN-Based Near-Ultraviolet and Blue-Light-Emitting Diodes with High External Quantum Efficiency Using a Patterned Sapphire Substrate and a Mesh Electrode; Jpn. J. Appl. Phys Vol. 41 (2002) pp. L1431-L1433, Part 2, No. 12B, December 15, 2002, The Japan Society of Applied Physics.									
EXAMINER				DATE CONSIDERED							
<b>EXAMINER:</b> Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.											